FAIRCHILD

SEMICONDUCTOR TM

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# MM88C29 • MM88C30 Quad Single-Ended Line Driver • Dual Differential Line Driver

#### **General Description**

The MM88C30 is a dual differential line driver that also performs the dual four-input NAND or dual four-input AND function. The absence of a clamp diode to  $V_{CC}$  in the input protection circuitry of the MM88C30 allows a CMOS user to interface systems operating at different voltage levels. Thus, a CMOS digital signal source can operate at a  $V_{CC}$  voltage greater than the  $V_{CC}$  voltage of the MM88C30 line driver. The differential output of the MM88C30 eliminates ground-loop errors.

The MM88C29 is a non-inverting single-wire transmission line driver. Since the output ON resistance is a low  $20\Omega$  typ., the device can be used to drive lamps, relays, solenoids, and clock lines, besides driving data lines.

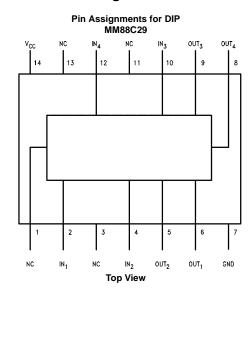
#### **Features**

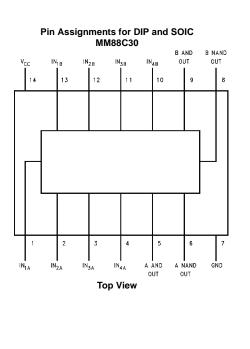
- Wide supply voltage range: 3V to 15V
- High noise immunity: 0.45 V<sub>CC</sub> (typ.)
- Low output ON resistance: 20Ω (typ.)

### **Ordering Code:**

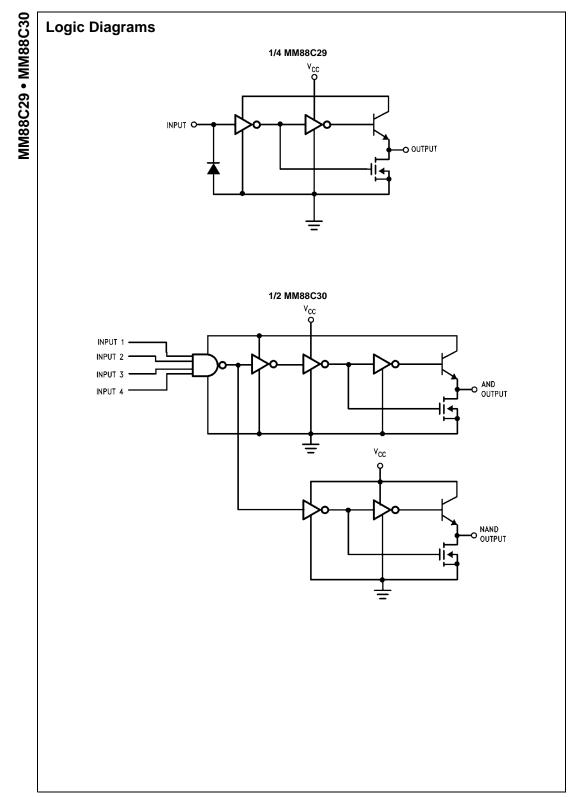
Order Number	Package Number	Package Description			
MM88C29N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
MM88C30M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
MM88C30N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.					

#### **Connection Diagrams**





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## Absolute Maximum Ratings(Note 1)

Voltage at Any Pin (Note 2)	-0.3V to V <sub>CC</sub> +16V
Operating Temperature Range	-40°C to +85°C
Storage Temperature	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation (P <sub>D</sub> )	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V <sub>CC</sub> Range	3V to 15V
Absolute Maximum $V_{CC}$	18V

Average Current at Output	
MM88C30	50 mA
MM88C29	25 mA
Maximum Junction Temperature, Tj	150°C
Lead Temperature	
(Soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: AC Parameters are guaranteed by DC correlated testing.

# **DC Electrical Characteristics**

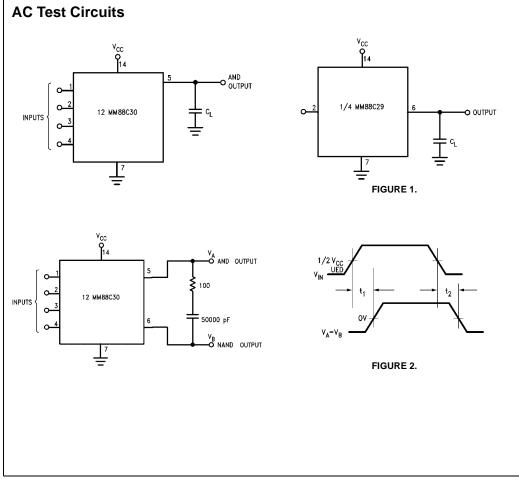
Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO	CMOS		4	<u>ا</u>		
V <sub>IN(1)</sub> Log	Logical "1" Input Voltage	$V_{CC} = 5V$	3.5			V
		$V_{CC} = 10V$	8			V
V <sub>IN(0)</sub>	Logical "0" Input Voltage	$V_{CC} = 5V$			1.5	V
		$V_{CC} = 10V$			2	V
I <sub>IN(1)</sub>	Logical "1" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V		0.005	1	μΑ
I <sub>IN(0)</sub>	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1	-0.005		μΑ
I <sub>CC</sub>	Supply Current	$V_{CC} = 5V$		0.05	100	mA
OUTPUT I	DRIVE		•			
ISOURCE	Output Source Current	$V_{OUT} = V_{CC} - 1.6V,$				
		$V_{CC} \ge 4.75V$ , $T_i = 25^{\circ}C$	-47	-80		mA
		T <sub>i</sub> = 85°C	-32	-60		mA
	MM88C29	$V_{OUT} = V_{CC} - 0.8V$	-2	-20		mA
	MM88C30	$V_{CC} \ge 4.5V$				
I <sub>SINK</sub>	Output Sink Current	$V_{OUT} = 0.4V, V_{CC} = 4.75V,$				
		$T_i = 25^{\circ}C$	9.5	22		mA
		$T_i = 85^{\circ}C$	8	18		mA
		$V_{OUT} = 0.4V, V_{CC} = 10V,$				
		$T_i = 25^{\circ}C$	19	40		mA
		T <sub>i</sub> = 125°C	15.5	33		mA
ISOURCE	Output Source Resistance	$V_{OUT} = V_{CC} - 1.6V,$				
		$V_{CC} \ge 4.75V$ , $T_j = 25^{\circ}C$		20	34	Ω
		$T_j = 85^{\circ}C$		27	50	Ω
I <sub>SINK</sub>	Output Sink Resistance	V <sub>OUT</sub> = 0.4V, V <sub>CC</sub> = 4.75V,				
		$T_j = 25^{\circ}C$		18	41	Ω
		$T_j = 85^{\circ}C$		22	50	Ω
		$V_{OUT} = 0.4V, V_{CC} = 10V,$				
		$T_j = 25^{\circ}C$		10	21	Ω
		$T_j = 85^{\circ}C$		12	26	Ω
	Output Resistance					
	Temperature Coefficient					
	Source			0.55		%/°C
	Sink			0.40		%/°C
θ <sub>JA</sub>	Thermal Resistance			150		°C/M
	(N-Package)					

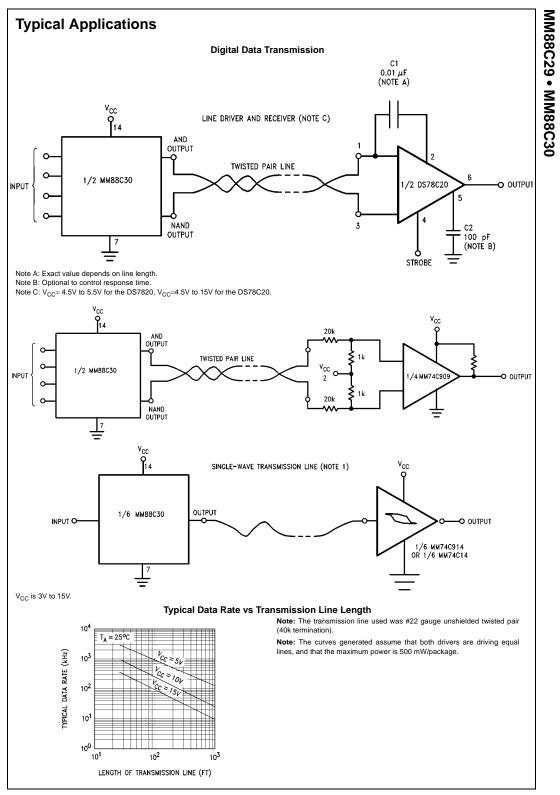
MM88C29 • MM88C30

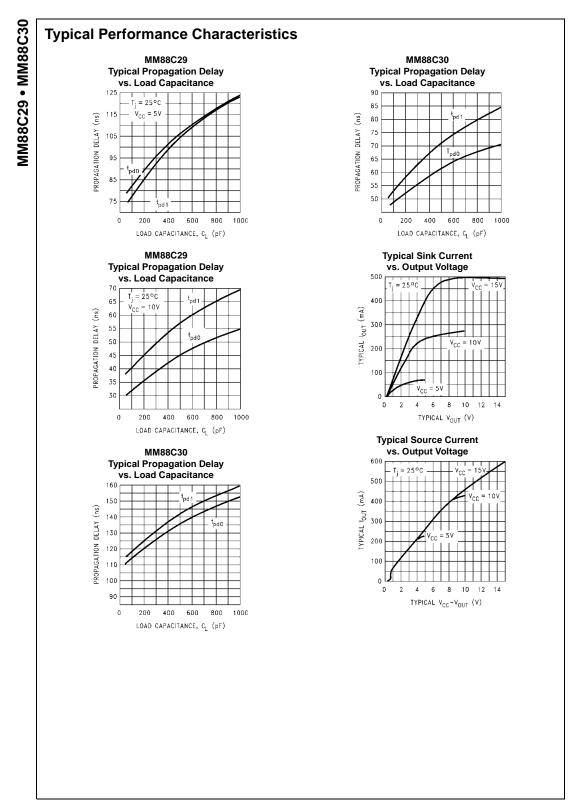
71	C, C <sub>L</sub> = 50 pF					
Symbol	Parameter	Conditions	Min	Тур	Мах	Un
t <sub>pd</sub>	Propagation Delay Time to					
	Logical "1" or "0"	(See Figure 1)				
	MM88C29	$V_{CC} = 5V$		80	200	n
		$V_{CC} = 10V$		35	100	n
	MM88C30	$V_{CC} = 5V$		110	350	n
		$V_{CC} = 10V$		50	150	n
t <sub>pd</sub>	Differential Propagation Delay	$R_L = 100\Omega, \ C_L = 5000 \ pF$				
	Time to Logical "1" or "0"	(See Figure 2)				
	MM88C30	$V_{CC} = 5V$			400	n
		$V_{CC} = 10V$			150	n
C <sub>IN</sub>	Input Capacitance					
	MM88C29	(Note 3)		5.0		p
	MM88C30	(Note 3)		5.0		p
C <sub>PD</sub>	Power Dissipation Capacitance		1			
	MM88C29	(Note 3)		150		p
	MM88C30	(Note 3)		200		pF

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: C<sub>PD</sub> determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics application note AN-90 (CMOS Logic Databook).

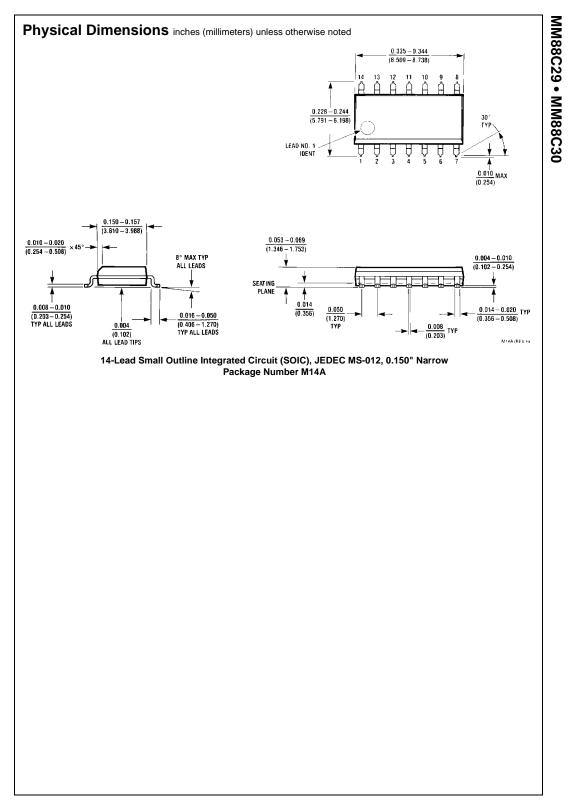


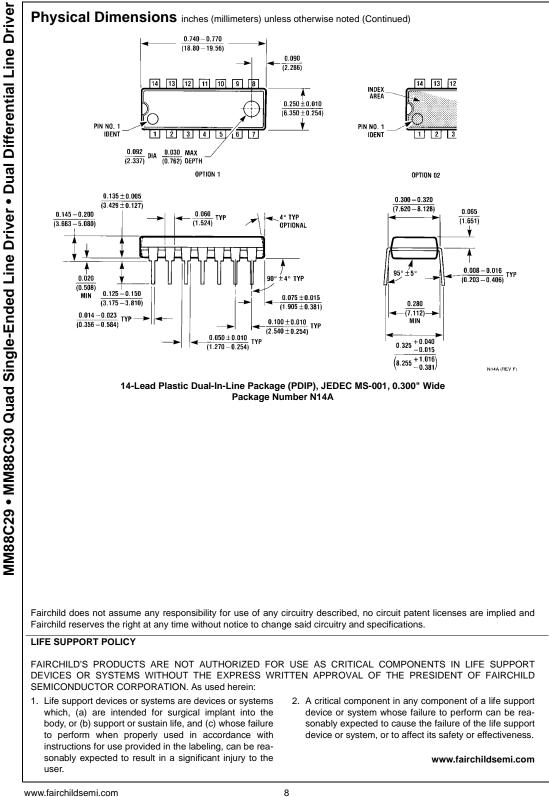




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